HEF4104B

Quad low-to-high voltage translator with 3-state outputs Rev. 9 — 29 March 2016 Product data

Product data sheet

General description 1.

The HEF4104B is a quad low voltage-to-high voltage translator with 3-state outputs. It provides the capability of interfacing low voltage circuits to high voltage circuits. For example low voltage Local Oxidation Complementary MOS (LOCMOS) and Transistor-Transistor Logic (TTL) to high voltage LOCMOS. It has four data inputs (A0 to A3), an active HIGH output enable input (OE), four data outputs (B0 to B3) and their complements (B0 to B3).

With OE = HIGH, the outputs B0 to B3 and $\overline{B}0$ to $\overline{B}3$ are in the low impedance ON-state, either HIGH or LOW as determined by the inputs A0 to A3. With OE = LOW, the outputs B0 to B3 and B0 to B3 are in the high-impedance OFF-state.

It uses a common negative supply (VSS) and separate positive supplies for the inputs $(V_{DD(A)})$ and the outputs $(V_{DD(B)})$. $V_{DD(A)}$ must always be less than or equal to $V_{DD(B)}$, even during power turn-on and turn-off. For the permissible operating range of V_{DD(A)} and V_{DD(B)} see Figure 4.

Each input protection circuit is terminated between $V_{\text{DD(B)}}$ and V_{SS} . This allows the input signals to be driven from any potential between V_{DD(B)} and V_{SS}, without regard to current limiting. When driving from potentials greater than $V_{DD(B)}$ or less than V_{SS} , the current at each input must be limited to 10 mA.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD}, V_{SS}, or another input.

2. Features and benefits

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Inputs and outputs are protected against electrostatic effects
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

Ordering information 3.

Table 1. **Ordering information**

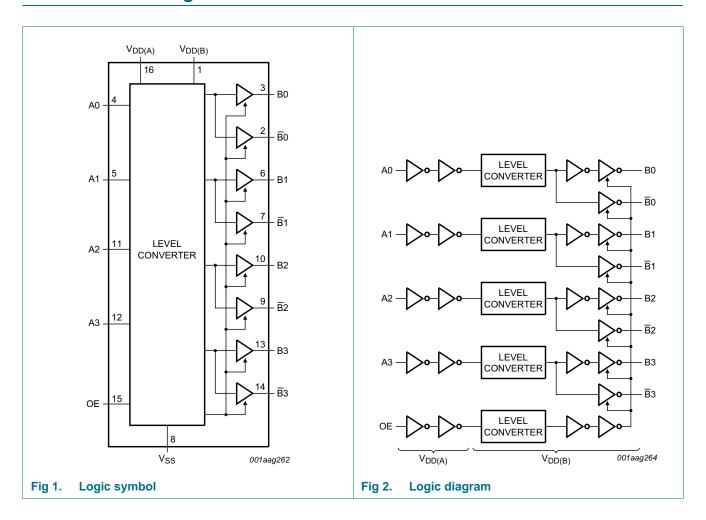
All types operate from $-40 \,^{\circ}\text{C}$ to $+85 \,^{\circ}\text{C}$.

Type number	Package Package									
	Name	Description	Version							
HEF4104BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1							



Quad low-to-high voltage translator with 3-state outputs

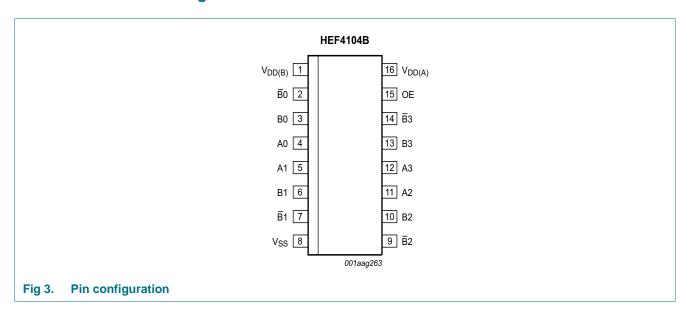
4. Functional diagram



Quad low-to-high voltage translator with 3-state outputs

5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
$V_{DD(B)}$	1	supply voltage port B
B0 to B3	2, 7, 9, 14	complementary data output
B0 to B3	3, 6, 10, 13	data output
A0 to A3	4, 5, 11, 12	data input
V _{SS}	8	common negative supply voltage (0 V)
OE	15	output enable input
$V_{DD(A)}$	16	supply voltage port A

6. Functional description

Table 3. Function table[1]

Control	Dutput				
OE	Bn	Bn			
Н	An	Ān			
L	Z	Z			

[1] H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF-state.

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground).

		, ,	3 , (, , 3			,
Symbol	Parameter	Conditions		Min	Max	Unit
$V_{DD(A)}$	supply voltage A	port A; $V_{DD(A)} \le V_{DD(B)}$		-0.5	+18	V
$V_{DD(B)}$	supply voltage B	port B; $V_{DD(B)} \ge V_{DD(A)}$		-0.5	+18	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD(A)} + 0.5 \text{ V}$		-	±10	mA
VI	input voltage			-0.5	$V_{DD(A)} + 0.5$	V
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{DD(B)} + 0.5 \text{ V}$		-	±10	mA
I _{I/O}	input/output current			-	±10	mA
I _{DD}	supply current		[1]	-	50	mA
T _{stg}	storage temperature			-65	+150	°C
T _{amb}	ambient temperature			-40	+85	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$				
		SO16	[2]	-	500	mW
Р	power dissipation	per output		-	100	mW

^[1] I_{DD} is the combined current of $I_{DD(A)}$ and $I_{DD(B)}$.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DD(A)}$	supply voltage A		3	-	$\leq V_{DD(B)}$	V
$V_{DD(B)}$	supply voltage B		$\geq V_{DD(A)}$	-	15	V
VI	input voltage		0	-	$V_{DD(A)}$	V
T _{amb}	ambient temperature	in free air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	V _{DD(A)} = 5 V	-	-	3.75	μs/V
		V _{DD(A)} = 10 V	-	-	0.5	μs/V
		V _{DD(A)} = 15 V	-	-	0.08	μs/V

^[2] For SO16 packages: above T_{amb} = 70 °C, P_{tot} derates linearly at 8 mW/K.

Quad low-to-high voltage translator with 3-state outputs

9. Static characteristics

Table 6. Static characteristics

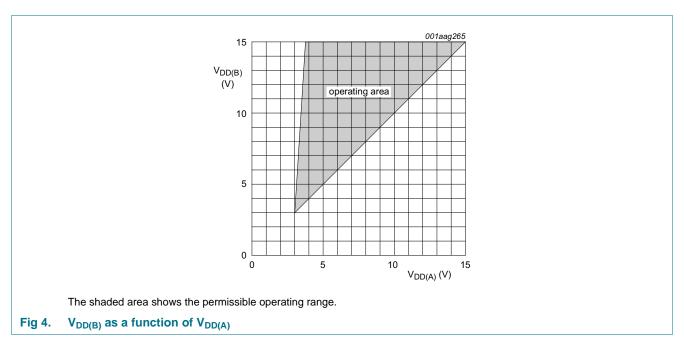
 $V_{DD(A)} = V_{DD(B)}$; $V_{SS} = 0$ V; $V_{I} = V_{SS}$ or $V_{DD(A)}$; unless otherwise specified.

Symbol	Parameter	Conditions	V _{DD} [1]	T _{amb} =	-40 °C	T _{amb} =	+25 °C	T _{amb} =	+85 °C	Unit
				Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level	I _O < 1 μA	5 V	3.5	-	3.5	-	3.5	-	V
	input voltage		10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V_{IL}	LOW-level	I _O < 1 μA	5 V	-	1.5	-	1.5	-	1.5	V
	input voltage		10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V _{OH}	HIGH-level	I _O < 1 μA	5 V	4.95	-	4.95	-	4.95	-	V
	output voltage	ut voltage	10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V_{OL}	LOW-level	I _O < 1 μA	5 V	-	0.05	-	0.05	-	0.05	V
	output voltage	ltage	10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level output current	V _O = 2.5 V	5 V	-	-1.7	-	-1.4	-	-1.1	mA
		V _O = 4.6 V	5 V	-	-0.52	-	-0.44	-	-0.36	mA
		V _O = 9.5 V	10 V	-	-1.3	-	-1.1	-	-0.9	mA
		V _O = 13.5 V	15 V	-	-3.6	-	-3.0	-	-2.4	mA
I _{OL}	LOW-level	V _O = 0.4 V	5 V	0.52	-	0.44	-	0.36	-	mA
	output current	V _O = 0.5 V	10 V	1.3	-	1.1	-	0.9	-	mA
		V _O = 1.5 V	15 V	3.6	-	3.0	-	2.4	-	mA
I _I	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	μΑ
I _{DD}	supply current	all valid input	5 V [2]	-	20	-	20	-	150	μΑ
		combinations;	10 V	-	40	-	40	-	300	μΑ
		I _O = 0 A	15 V	-	80	-	80	-	600	μΑ
l _{OZ}	OFF-state output current	HIGH level; $V_O = V_{DD(B)}$	15 V	-	1.6	-	1.6	-	12.0	μΑ
		LOW level; V _O = V _{SS}	15 V	-	-1.6	-	-1.6	-	-12.0	μΑ
Cı	input capacitance	digital inputs	-	-	-	-	7.5	-	-	рF

^[1] V_{DD} is the same as $V_{DD(A)}$ and $V_{DD(B)}$.

^[2] I_{DD} is the combined current of $I_{DD(A)}$ and $I_{DD(B)}$.

Quad low-to-high voltage translator with 3-state outputs



10. Dynamic characteristics

Table 7. Dynamic characteristics

 T_{amb} = 25 °C; for test circuit see <u>Figure 7</u>; unless otherwise specified.

Symbol	Parameter	Conditions	Extrapolation formula[1]	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW	An to Bn, Bn; see Figure 5					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$	143 ns + (0.55 ns/pF)C _L	-	170	340	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$	69 ns + (0.23 ns/pF)C _L	-	80	160	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$	57 ns + (0.16 ns/pF)C _L	-	65	135	ns
t _{PLH} L	LOW to HIGH	An to Bn, Bn; see Figure 5					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$	143 ns + (0.55 ns/pF)C _L	-	170	340	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$	69 ns + (0.23 ns/pF)C _L	-	80	160	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$	62 ns + (0.16 ns/pF)C _L	-	70	140	ns
t _{THL}	HIGH to LOW output transition time	Bn or Bn; see Figure 6					
		$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$	10 ns + (1.00 ns/pF)C _L	-	60	120	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$	9 ns + (0.42 ns/pF)C _L	-	30	60	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$	6 ns + (0.28 ns/pF)C _L	-	20	40	ns
t _{TLH}	LOW to HIGH output	Bn or Bn; see Figure 6					
	transition time	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$	10 ns + (1.00 ns/pF)C _L	-	60	120	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$	9 ns + (0.42 ns/pF)C _L	-	30	60	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$	6 ns + (0.28 ns/pF)C _L	-	20	40	ns
t _{PHZ}	HIGH to OFF-state	OE to Bn, Bn; see Figure 6					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$		-	70	135	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$		-	55	110	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$		-	60	120	ns

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 Table 7.
 Dynamic characteristics ...continued

 $T_{amb} = 25$ °C; for test circuit see <u>Figure 7</u>; unless otherwise specified.

Symbol	Parameter	Conditions	Extrapolation formula[1]	Min	Тур	Max	Unit
t _{PLZ} LOW to OFF-state		OE to Bn, Bn; see Figure 6					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$		-	70	135	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$		-	55	105	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$		-	55	110	ns
t _{PZH}	OFF-state to HIGH	OE to Bn, Bn; see Figure 6					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$		-	195	395	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$		-	95	195	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$		-	80	165	ns
t _{PZL}	OFF-state to LOW	OE to Bn, Bn; see Figure 6					
	propagation delay	$V_{DD(A)} = V_{DD(B)} = 5 \text{ V}$		-	195	395	ns
		$V_{DD(A)} = V_{DD(B)} = 10 \text{ V}$		-	95	190	ns
		$V_{DD(A)} = V_{DD(B)} = 15 \text{ V}$		-	80	160	ns

^[1] Typical value of the propagation delay and output transition time can be calculated with the extrapolation formula (C_L in pF).

Table 8. Dynamic power dissipation

 $V_{DD(A)} = V_{DD(B)}$; $V_{SS} = 0$ V; $t_f = t_f \le 20$ ns; $T_{amb} = 25$ °C.

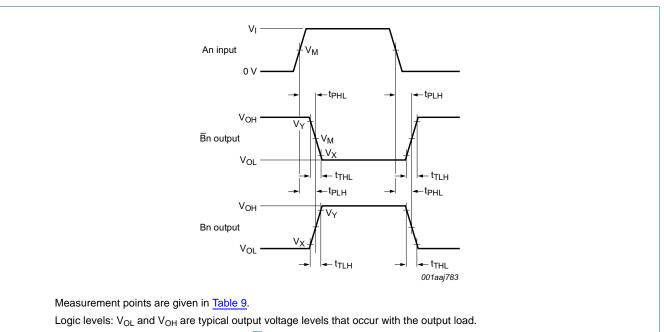
. ,	1 /			
Symbol	Parameter	V DD[1]	Typical formula (μW)	where
P_D	dynamic power	5 V	$P_D = 3000 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$	f _i = input frequency in MHz;
	dissipation	10 V	$P_D = 12200 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$	fo = output frequency in MHz;
		15 V	$P_D = 31000 \times f_i + \Sigma (f_0 \times C_L) \times V_{DD}^2$	C _L = output load capacitance in pF;
				$\Sigma(f_o \times C_L)$ = sum of the outputs;
				V _{DD} = supply voltage in V.

^[1] V_{DD} is the same as $V_{DD(A)}$ and $V_{DD(B)}$.

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Quad low-to-high voltage translator with 3-state outputs

11. Waveforms



Data input (An) to data output (Bn, Bn) propagation delays and output transition times Fig 5.

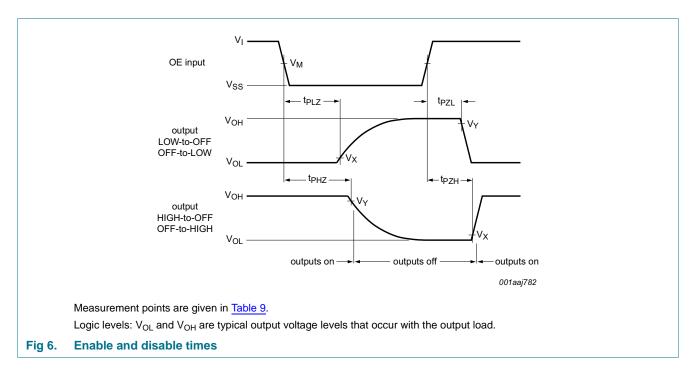


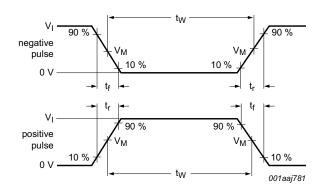
Table 9. **Measurement points**

Input		Output			
V _I	V _M	V _M	V _X	V _Y	
V _{SS} or V _{DD(A)}	0.5V _{DD(A)}	0.5V _{DD(B)}	0.1V _{DD(B)}	0.9V _{DD(B)}	

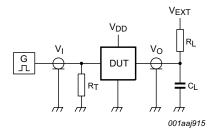
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a. Input waveforms



b. Test circuit

Test data given in Table 10.

Definitions for test circuit:

DUT = Device Under Test.

 C_L = load capacitance including jig and probe capacitance.

 R_L = load resistance.

 R_T = termination resistance should be equal to the output impedance Z_0 of the pulse generator.

Fig 7. Test circuit for measuring switching times

Table 10. Test data

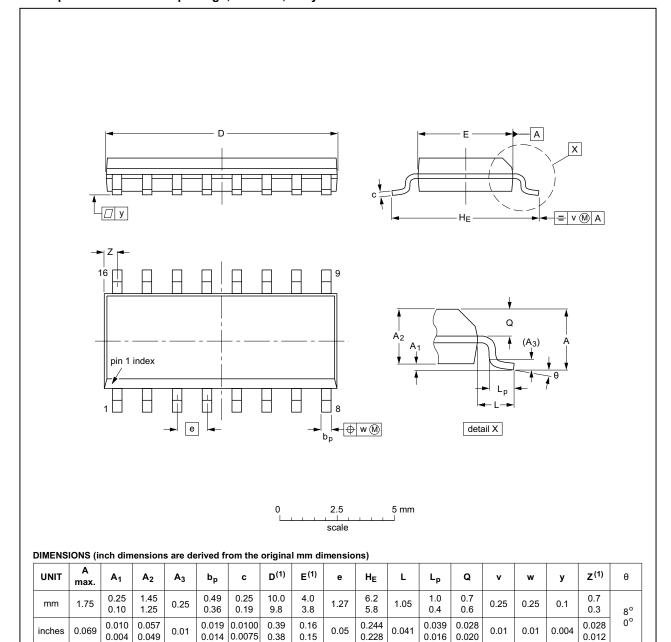
Supplies	Input	Load		V _{EXT}		
$V_{DD(A)} = V_{DD(B)}$	t _r , t _f	R_L	CL	t _{PHL} , t _{PLH} t _{PZL} , t _{PLZ} t _{PZH} , t _{PHZ}		
5 V to 15 V	≤ 20 ns	1 kΩ	50 pF	open	$V_{DD(B)}$	V _{SS}

Quad low-to-high voltage translator with 3-state outputs

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012			99-12-27 03-02-19	

Fig 8. Package outline SOT109-1 (SO16)

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13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
HEF4104B v.9	20160329	Product data sheet	-	HEF4104B v.8	
Modifications:	Type number HEF4104BP (SOT38-4) removed.				
HEF4104B v.8	20111111	Product data sheet	-	HEF4104B v.7	
Modifications:	Section Applications removed				
	<u>Table 6</u> : I _{OH} minimum values changed to maximum				
HEF4104B v.7	20091216	Product data sheet	-	HEF4104B v.6	
HEF4104B v.6	20091102	Product data sheet	-	HEF4104B v.5	
HEF4104B v.5	20090728	Product data sheet	-	HEF4104B v.4	
HEF4104B v.4	20090305	Product data sheet	-	HEF4104B_CNV v.3	
HEF4104B_CNV v.3	19950101	Product specification	-	HEF4104B_CNV v.2	
HEF4104B_CNV v.2	19950101	Product specification	-	-	

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14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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